

OM-X8GXXXXX-X Series HF/UHF OCXO Low Power

Rev. K

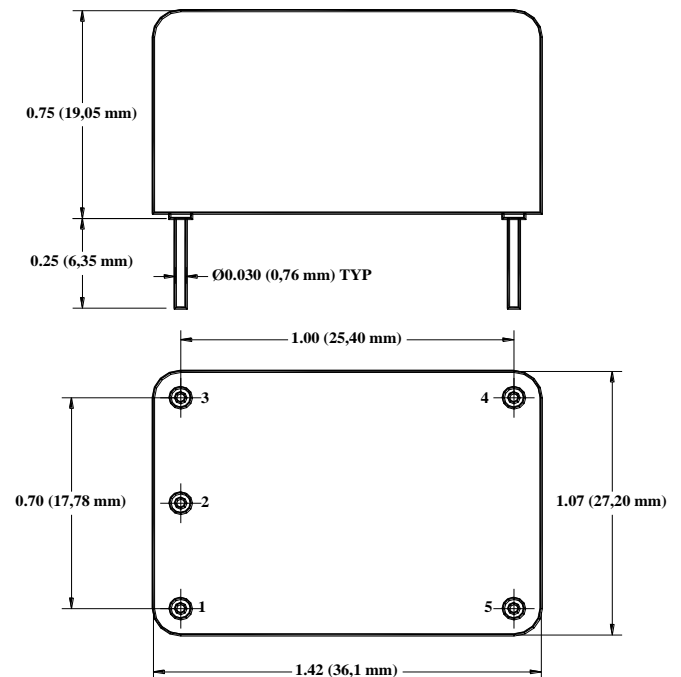
Product Data Sheet

Description:

The OM-X8GXXXXX Series of Oven Controlled Crystal Oscillators (OCXO) provides High and Ultra High Frequency with SC-cut stability performance, extremely low phase noise and power consumption, with either CMOS or Sine-wave output in a standard 1.4x1" package – "Europack".

Features

- Very Low Power Consumption
- Very Low Phase Noise
- Excellent SC-cut Frequency Stability
- Ultra High Frequency – up to 1 GHz
- CMOS, Sine-Wave outputs available
- Stratum3E available
- COTS/Dual use



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Specifications:

Parameter	Symb	Condition	Min	Typ	Max	Unit	Note
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Absolute Maximum Ratings

Input Break Down Voltage	Vcc		-0.5		5.5	V	
Storage temp.	Ts		-40		85	°C	
Contr. Voltage	Vc		1		9	V	

Electrical (1)

Frequency Range	F	CMOS Sine-wave	30 30		200 1,000	MHz		
Input Voltage	Vcc		3.135 4.75	3.30 5.0	3.465 5.25	V	A 0	
Input Current	Icc				90 160	mA	@ 100 MHz, 3.3V @ 622 MHz, 3.3V	
Frequency Stability	ΔF/F	vs. Temperature vs. Vcc aging		±50 ±2 ±0.1 ±0.5		ppb ppb/V ppm/year ppm	See chart First Year 15 years	
Calibration	ΔF/F	As shipped, 25°C		±0.1		ppm		
Load		CMOS Sine	15pF/10KOhm Internally AC-coupled 50 Ohm					
Duty cycle		@50%	45	50	55	%	CMOS	
Rise/Fall time	Tr/Tf	20 to 80 %		3		ns	CMOS	
Logic "1" level	Voh	CMOS	0.9Vcc			V		
Logic "0" level	Vol	CMOS			0.1Vcc	V		
Output power	P	Sinewave Into 50 Ohm	0 4	3 7		dBm	3.3V 5.0V	
Start up time	Ts			2	10	ms		
Phase jitter		1σ		0.4 0.2	1 0.4	ps	100 Hz to 20 MHz 12 KHz to 20 MHz	
Subharmonics		Sine CMOS, Sine		-45	-40 none	dBc	F>250MHz F< 250 MHz	
Spurious					-60	dBc		
Harmonics		Sine-wave		-30	-25	dBc		
SSB Phase Noise		@ 10 Hz @ 100 Hz @ 1 KHz @ 10 KHz @ 100 KHz		-100 -120 -140 -160 -165		dBc/Hz	@ 100 MHz	
SSB Phase Noise		@ 10 Hz @ 100 Hz @ 1 KHz @ 10 KHz @ 100 KHz		-80 -90 -120 -145 -150		dBc/Hz	@ 622 MHz; Sine	
Input Impedance			> 10KOhm					
Control voltage	Vc		0 0		4.0 2.8	V V	Vcc code "0" Vcc code "A"	
Modulation bandwidth	MB		DC		1	KHz	Note 2	
Deviation		0V to Vc max	±0.5	±1.0		ppm		

Note 1. All parameters, unless otherwise specified, are at nominal conditions, ie: T=25°C, Nominal Vcc & Nominal Load.
 Note 2. Older and stock units may have MBW of 150 Hz Max.

Environmental and Mechanical

Operating temp. range	0°C to 70°C, -40°C to 85°C, see chart, page 1
Mechanical Shock	Per MIL-STD-202, Method 213, Cond. E
Thermal Shock	Per MIL-STD-883, Method 1011, Cond. A
Vibration	Per MIL-STD-883, Method 2007, Cond. A
Soldering Conditions	260°C for 10 s leads only
Hermetic Seal	Leak rate less than 5x10 ⁻⁸ atm.cc/s of helium

Electrical Connections

Pin Out	Pin #1 - Voltage Control ; Pin #2 - Vref ; Pin #3 - Vcc; Pin#4 - Output, CMOS or Sine; Pin#5 - GND
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Creating a Part Number

OM - X 8G X X XX X - X - FREQ

Package Code

OM 5 pin 36 x 27x19mm high

Supply Voltage

Code	Specification
0	5V ±5%
A	3.3V ±5%

OCXO/OCVCXO Option

Code	Specification
X	No V. Control
V	W/ V. Control

Output Type

Code	Specification
C	CMOS
S	Sine-wave

Temperature Stability

Code	Specification
17	1x10 ⁻⁷
58	5x10 ⁻⁸
28	2x10 ⁻⁸
18	1x10 ⁻⁸
YZ	Yx10 ^{-Z}

Environmental

Code	Specification
L	Contains a level of lead that is in excess of RoHS directive and is not designed for reflow
R	RoHS compliant, not designed for reflow

Temperature Range

Code	Specification
A	0°C to 50°C
B	0°C to 70°C
C	-20°C to 70°C
D	-40°C to 85°C
E	-10°C to 60°C
F	-40°C to 80°C
G	-30°C to 70°C